

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P82AK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

General Features

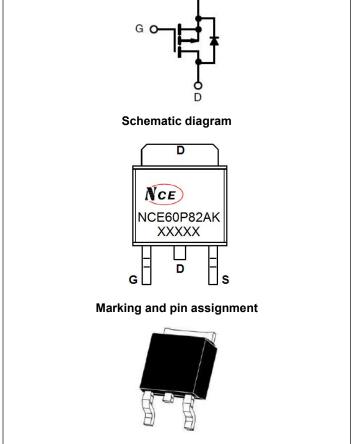
- V_{DS} =-60V,I_D =-82A
 R_{DS(ON)} <13mΩ @ V_{GS}=-10V
 R_{DS(ON)} <16mΩ @ V_{GS}=-4.5V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAs
- Excellent package for good heat dissipation

Application

Load switch

100% UIS TESTED!

100% ΔVds TESTED!



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TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P82AK	NCE60P82AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-60	V	
Gate-Source Voltage	Vgs	±20	V	
Drain Current-Continuous	Ι _D	-82	А	
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	-58	A	
Pulsed Drain Current	I _{DM}	-328	A	
Maximum Power Dissipation	PD	150	W	
Derating factor		1.0	W /℃	
Single pulse avalanche energy (Note 5)	E _{AS}	722	mJ	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C	



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	Rejc	1.0	°C/W
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Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	I					
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V,V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	I					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =-250µA	-1.2	-1.8	-2.4	V
Drain Course On Chata Desistence		V _{GS} =-10V, I _D =-20A	-	11	13	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-4.5V, I _D =-20A	-	13	16	mΩ
Forward Transconductance	g Fs	V _{DS} =-5V,I _D =-20A	-	25	-	S
Dynamic Characteristics (Note4)	·	·				
Input Capacitance	C _{lss}	- V _{DS} =-30V,V _{GS} =0V, F=1.0MHz	-	5604	-	PF
Output Capacitance	Coss		-	356	-	PF
Reverse Transfer Capacitance	Crss		-	265	-	PF
Switching Characteristics (Note 4)	·	·				
Turn-on Delay Time	t _{d(on)}		-	18	-	nS
Turn-on Rise Time	tr	V _{DD} =-30V, R _L =1.5Ω, V _{GS} =-10V,R _G =3Ω	-	20	-	nS
Turn-Off Delay Time	t _{d(off)}		-	55	-	nS
Turn-Off Fall Time	t _f		-	35	-	nS
Total Gate Charge	Qg	V _{DS} =-30,I _D =-20A,	-	62.1		nC
Gate-Source Charge	Q _{gs}		-	9.3		nC
Gate-Drain Charge	Q _{gd}	- V _{GS} =-10V	-	16.8		nC
Drain-Source Diode Characteristics						•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =-20A	-		-1.2	V
Diode Forward Current (Note 2)	Is		-	-	-82	А
Reverse Recovery Time	t _{rr}	TJ = 25°C, I _F =-20A	-	49		nS
Reverse Recovery Charge	Qrr	di/dt = -100A/µs ^(Note3)	-	71		nC
Forward Turn-On Time	ton	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t \leq 10 sec.

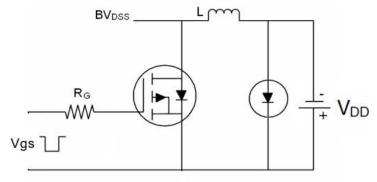
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

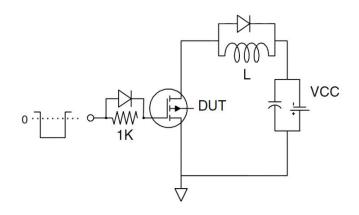
^{5.} EAS condition: Tj=25 $^\circ \!\! C$,V_DD=-30V,VG=-10V,L=0.5mH,Rg=25 Ω



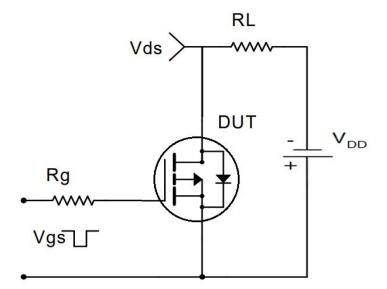
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

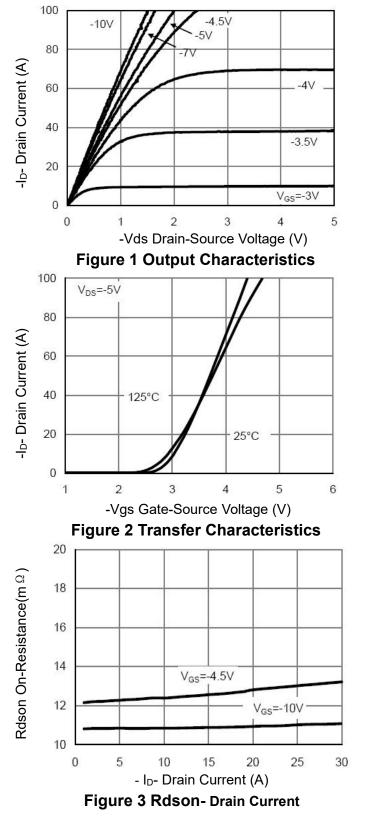


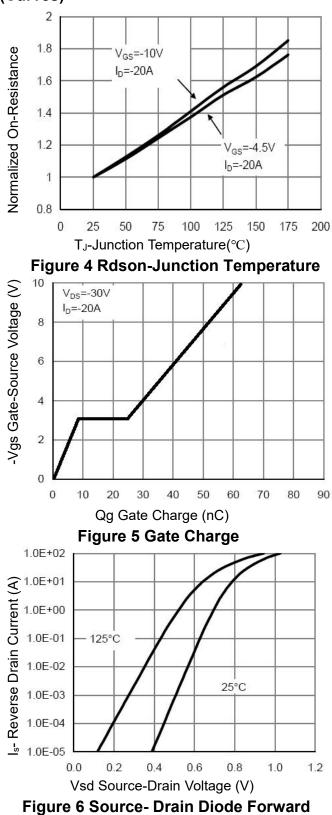
3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves)







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NCE60P82AK

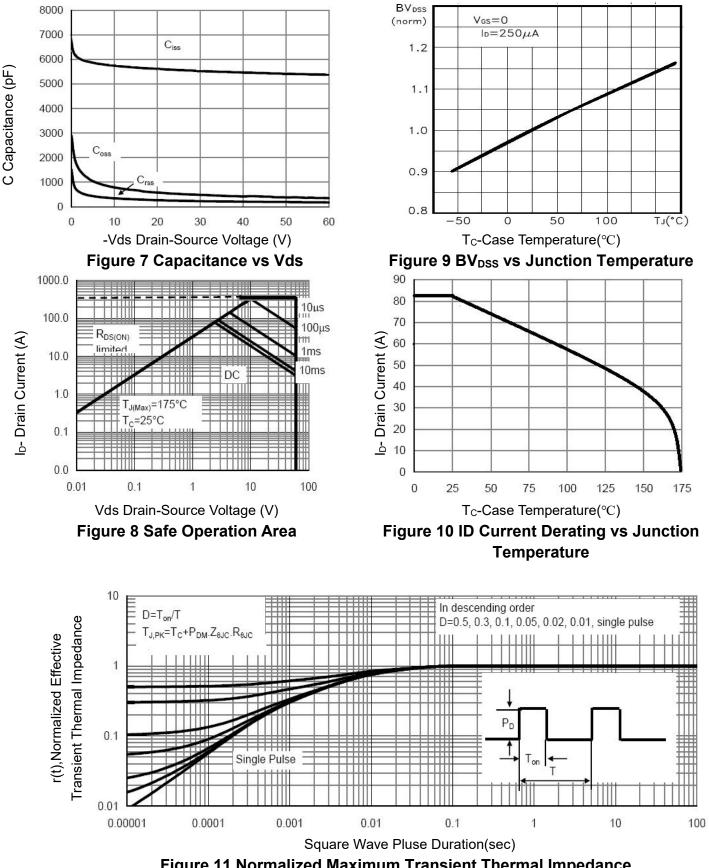
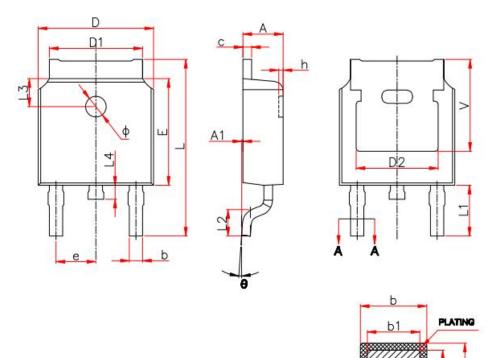


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252 Package Information



BASE METAL

SECTION A-A

Sumbol	Millimeters			
Symbol	Min.	Max.		
Α	2.20	2.40		
A1	0.00	0.13		
b	0.66	0.86		
b1	0.73	0.79		
С	0.46	0.58		
c1	0.50	0.52		
D	6.50	6.70		
D1	5.10	5.46		
D2	4.83 REF.			
E	6.00	6.20		
е	2.19	2.39		
L	9.80 10.40			
L1	2.90 REF.			
L2	1.40	1.70		
L3	1.60 REF.			
L4	0.60	1.00		
Φ	1.10	1.30		
θ	0°	8°		
h	0.00	0.30		
V	5.35 REF.			



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